

# PUMH10-Q

# NPN/NPN resistor-equipped double transistors; R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$

25 October 2021

Product data sheet

# 1. General description

NPN/NPN Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

# 3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replaces general-purpose transistors in digital applications

### 4. Quick reference data

Table 1. Quick reference data

	TOTOTOTIOG data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	*						'
$V_{CEO}$	collector-emitter voltage	open base		-	-	50	V
I <sub>O</sub>	output current			-	-	100	mA
R1	bias resistor 1		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	17	21	26	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



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# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1		
3	O2	output (collector) TR2	6 5 4	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		TR1
6	01	output (collector) TR1	□1 □2 □3	
			TSSOP6 (SOT363)	
				GND1 I1 O2 sym063

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package					
	Name	Description	Version			
PUMH10-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363			

# 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH10-Q	Н%О

[1] % = placeholder for manufacturing site code

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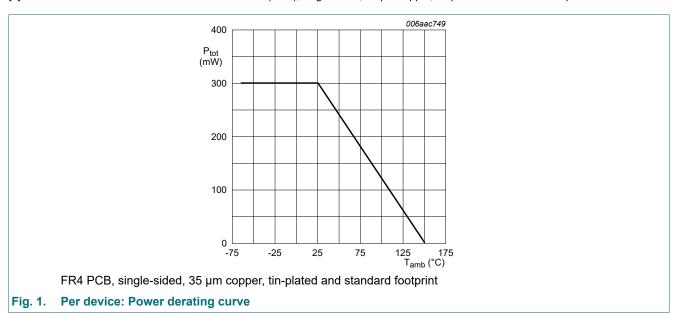
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'	•		
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
VI	input voltage	positive		-	12	V
		negative		-	-5	V
Io	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
Per device	<u> </u>		'	'		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



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# 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

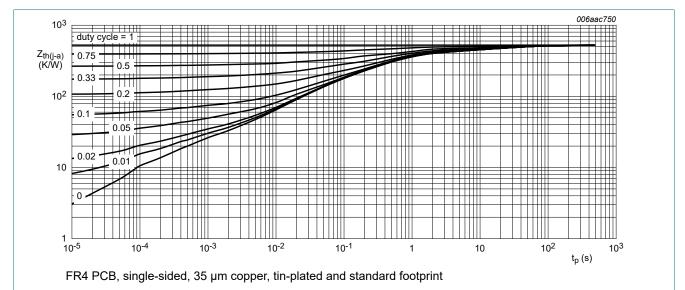


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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# 10. Characteristics

**Table 7. Characteristics** 

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
$V_{(BR)CBO}$	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A		-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A		-	-	100	nA
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A		-	-	180	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 5 mA; I <sub>B</sub> = 0.25 mA		-	-	100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA		-	0.6	0.5	V
V <sub>I(on)</sub>	on-state input voltage	V <sub>CE</sub> = 0.3 V; I <sub>C</sub> = 5 mA		1.1	0.75	-	V
R1	bias resistor 1		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	17	21	26	
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz		-	-	2.5	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	[2]	-	230	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor

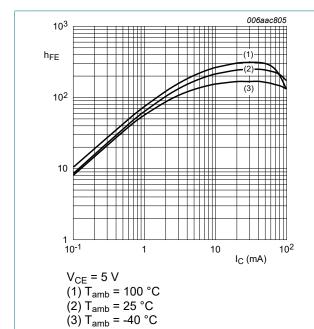
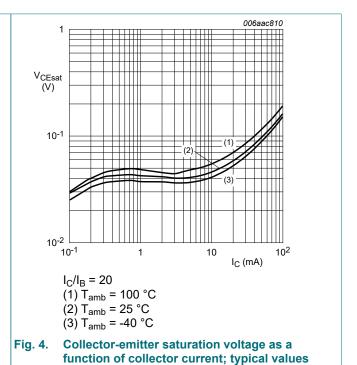
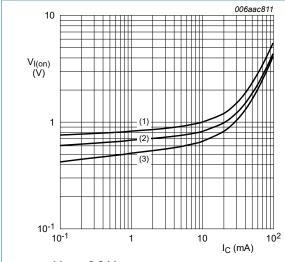


Fig. 3. DC current gain as a function of collector current; typical values

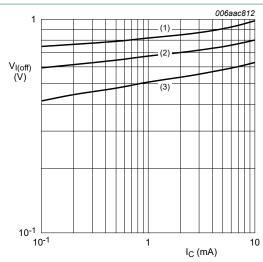


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V<sub>CE</sub> = 0.3 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

Fig. 5. current; typical values



V<sub>CE</sub> = 5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

On-state input voltage as a function of collector | Fig. 6. Off-state input voltage as a function of collector current; typical values

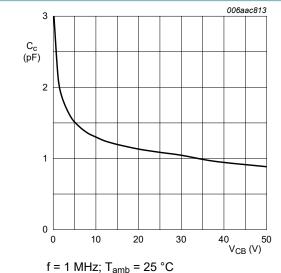
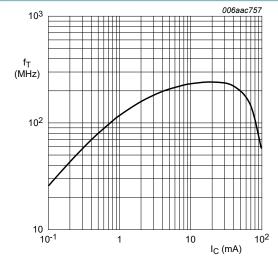


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values



f = 100 MHz  $T_{amb} = 25 \, ^{\circ}C$ 

 $V_{CE} = 5 V$ 

Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

NPN/NPN resistor-equipped double transistors; R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$ 

# 11. Test information

#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

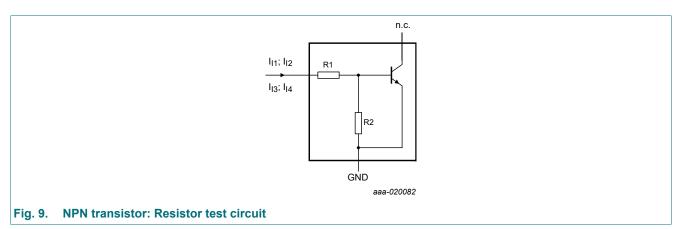
#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$



**Resistor test conditions** 

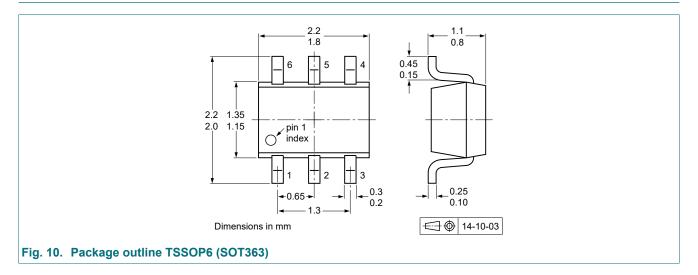
### Table 8. Resistor test conditions

Type number	Test conditions						
	I <sub>11</sub>	I <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>			
PUMH10-Q	90 μΑ	140 µA	-55 µA	-105 µA			

Product data sheet 25 October 2021 7 / 12

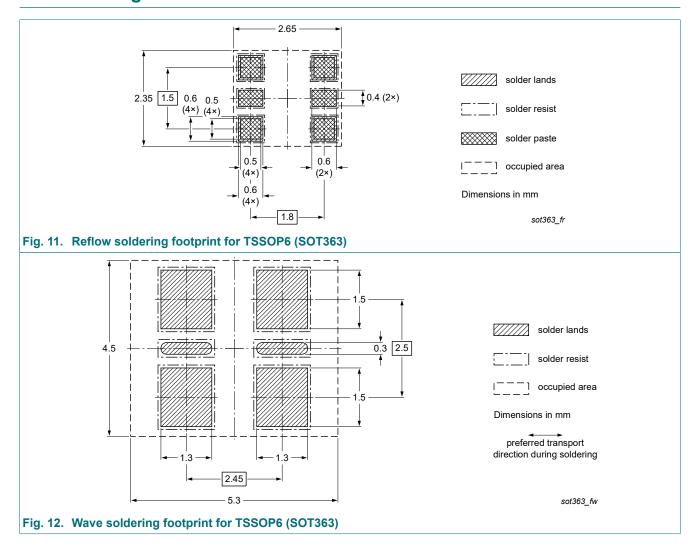
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# 12. Package outline



# NPN/NPN resistor-equipped double transistors; R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$

# 13. Soldering



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# 14. Revision history

### Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH10-Q v.1	20211025	Product data sheet	-	-

#### NPN/NPN resistor-equipped double transistors; R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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PUMH10-Q

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# **Contents**

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	Characteristics	5
11.	Test information	7
12.	Package outline	8
	Soldering	
14.	Revision history	10
	Legal information	
	-	

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